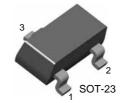
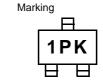


MMBT2222AK

NPN Epitaxial Silicon Transistor

General Purpose Transistor





1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings $T_a = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|----------------------------------|--|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 75 | V |
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 6 | V |
| I _C | Collector Current | 600 | mA |
| P _C | Collector Power Dissipation | 350 | mW |
| T _{J,} T _{STG} | Operating Junction and Storage Temperature Range | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|-----------------------|--|---|-----------------------------|------------|--------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 75 | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 10mA, I _B = 0 | 40 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu A, I_C = 0$ | 6 | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} = 60V, I _E = 0 | | 0.01 | μΑ |
| h _{FE} | DC Current Gain * | $\begin{split} &V_{CE} = 10V, I_C = 0.1 \text{mA} \\ &V_{CE} = 10V, I_C = 1 \text{mA} \\ &V_{CE} = 10V, I_C = 10 \text{mA} \\ &V_{CE} = 10V, I_C = 150 \text{mA} \\ &V_{CE} = 10V, I_C = 500 \text{mA} \end{split}$ | 35 50 75 100 40 | 300 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage * | I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA | | 0.3 1.0 | V V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage * | $I_C = 150$ mA, $I_B = 15$ mA $I_C = 500$ mA, $I_B = 50$ mA | 0.6 | 1.2 2.0 | V V |
| f _T | Current Gain Bandwidth Product | I _C = 20mA, V _{CE} = 20V, f = 100MHz | 300 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} = 10V, I _E = 0, f = 1MHz | | 8 | pF |
| NF | Noise Figure | $I_C = 100\mu A$, $V_{CE} = 10V$ 4 $R_S = 1K\Omega$, $f = 1MHz$ | | 4 | dB |
| t _{ON} | Turn On Time | $V_{CC} = 30V, I_{C} = 150mA$ 35 $V_{BE} = 0.5V, I_{B1} = 15mA$ | | ns | |
| t _{OFF} | Turn Off Time | $V_{CC} = 30V, I_C = 150mA,$ $I_{B1} = I_{B2} = 15mA$ | | 285 | ns |

^{*} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%

Typical Performance Characteristics

Figure 1. DC Current Gain

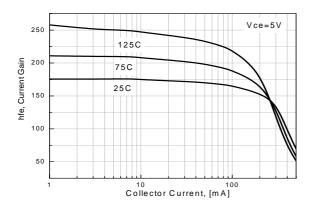


Figure 2. Collector- Emitter Saturation Voltage

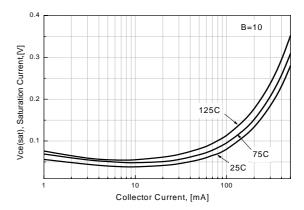


Figure 3. Base-Emitter Saturation Voltage

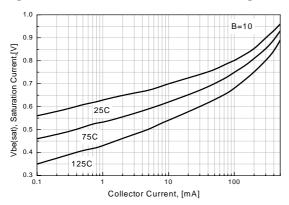


Figure 4. Collector - Base Leakage Current

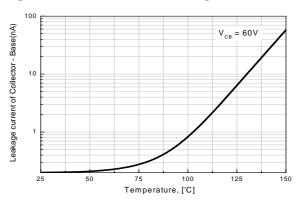


Figure 5. Output Capacitance

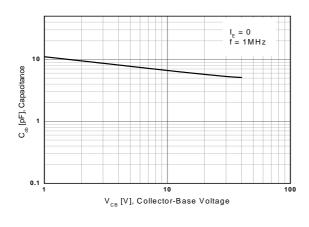
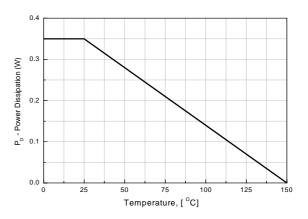


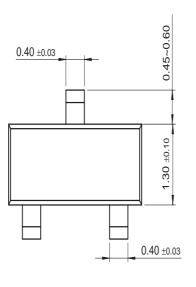
Figure 6. Power Dissipation vs
Ambient Temperature

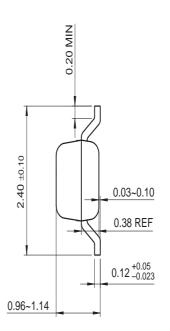


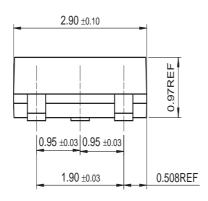
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Mechanical Dimensions

SOT-23







Dimensions in Millimeters

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